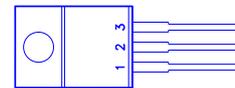
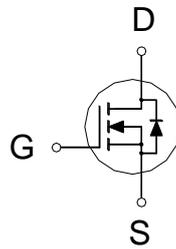




PRODUCT SUMMARY

$V_{(BR)DSS}$	$R_{DS(ON)}$	I_D
100V	10.5mΩ	69A



- 1. GATE
- 2. DRAIN
- 3. SOURCE

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		V_{DS}	100	V
Gate-Source Voltage		V_{GS}	±25	V
Continuous Drain Current	$T_C = 25^\circ\text{C}$	I_D	69	A
	$T_C = 100^\circ\text{C}$		49	
Pulsed Drain Current ¹		I_{DM}	200	
Avalanche Current		I_{AS}	23	
Avalanche Energy	$L = 1\text{mH}$	E_{AS}	264	mJ
Power Dissipation	$T_C = 25^\circ\text{C}$	P_D	115	W
	$T_C = 100^\circ\text{C}$		58	
Operating Junction & Storage Temperature Range		T_j, T_{stg}	-55 to 175	°C

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Case	$R_{\theta JC}$		1.3	°C / W
Junction-to-Ambient	$R_{\theta JA}$		50	

¹Pulse width limited by maximum junction temperature.

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, Unless Otherwise Noted)

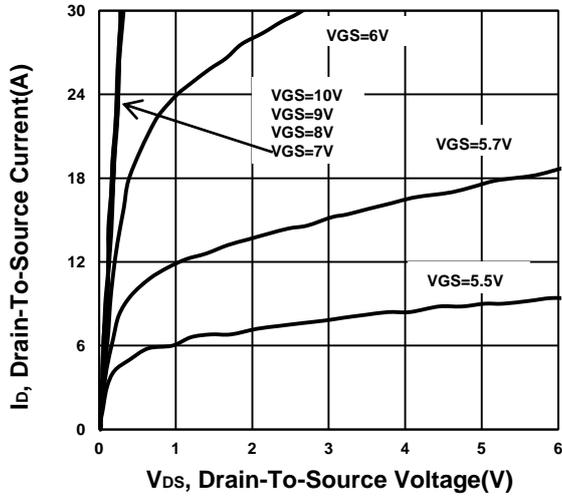
PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu\text{A}$	100			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	2.5	3.5	4.5	V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 25V$			±100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 80V, V_{GS} = 0V$			1	μA
		$V_{DS} = 80V, V_{GS} = 0V, T_J = 125^\circ\text{C}$			10	

Drain-Source On-State Resistance ¹	$R_{DS(ON)}$	$V_{GS} = 10V, I_D = 20A$	8.2	10.5	mΩ
		$V_{GS} = 7V, I_D = 20A$	9.9	13.5	
Forward Transconductance ¹	g_{fs}	$V_{DS} = 5V, I_D = 20A$	57		S
DYNAMIC					
Input Capacitance	C_{iss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$	4863		pF
Output Capacitance	C_{oss}		375		
Reverse Transfer Capacitance	C_{rss}		297		
Gate Resistance	R_g	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$	0.8		Ω
Total Gate Charge ²	Q_g	$V_{DS} = 50V, I_D = 20A$	$V_{GS} = 10V$	101	nC
			$V_{GS} = 7V$	76	
Gate-Source Charge ²	Q_{gs}		28		
Gate-Drain Charge ²	Q_{gd}		39		
Turn-On Delay Time ²	$t_{d(on)}$		41	nS	
Rise Time ²	t_r		99		
Turn-Off Delay Time ²	$t_{d(off)}$		93		
Fall Time ²	t_f		64		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_J = 25\text{ °C}$)					
Continuous Current ³	I_S			63	A
Forward Voltage ¹	V_{SD}	$I_F = 20A, V_{GS} = 0V$		1.2	V
Reverse Recovery Time	t_{rr}	$I_F = 20A, di_F/dt = 100A/\mu s$	46		nS
Reverse Recovery Charge	Q_{rr}		69		nC

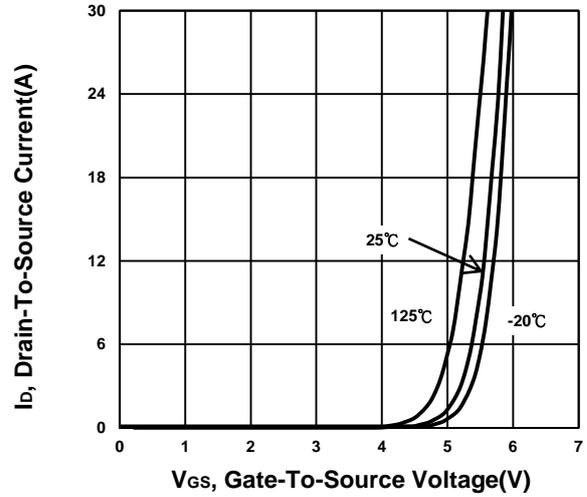
¹Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.

²Independent of operating temperature.

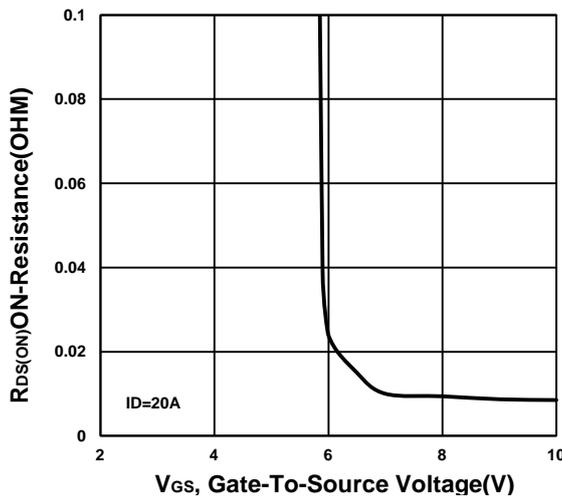
Output Characteristics



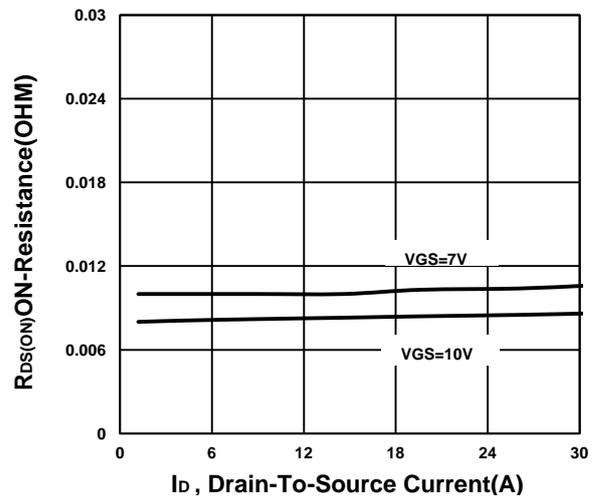
Transfer Characteristics



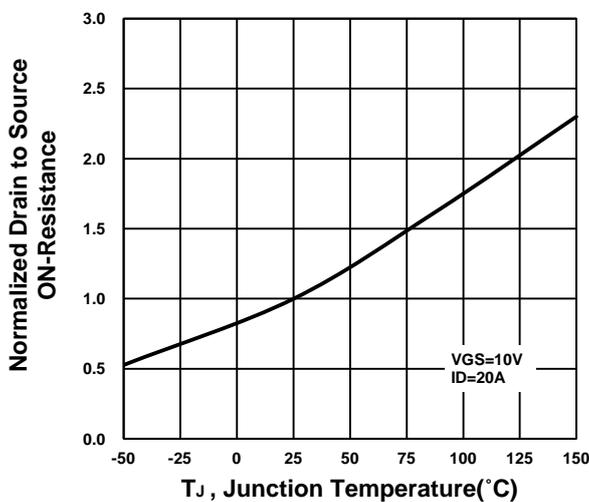
On-Resistance VS Gate-To-Source



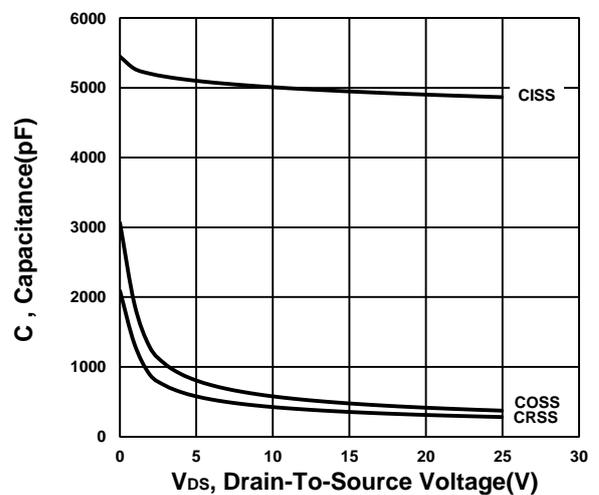
On-Resistance VS Drain Current



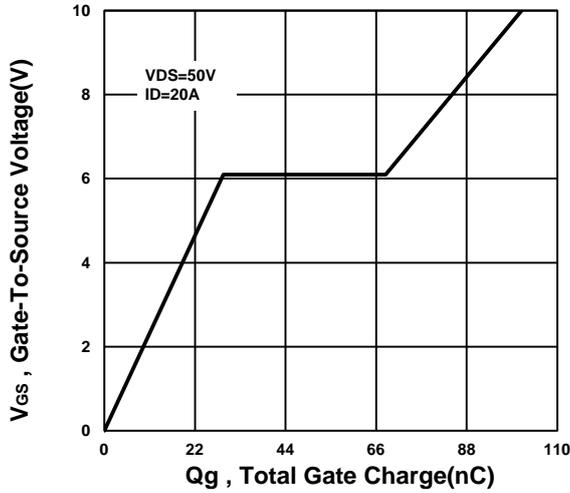
On-Resistance VS Temperature



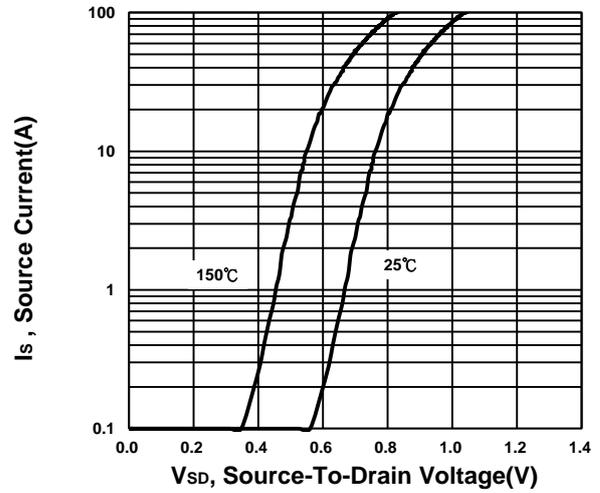
Capacitance Characteristic



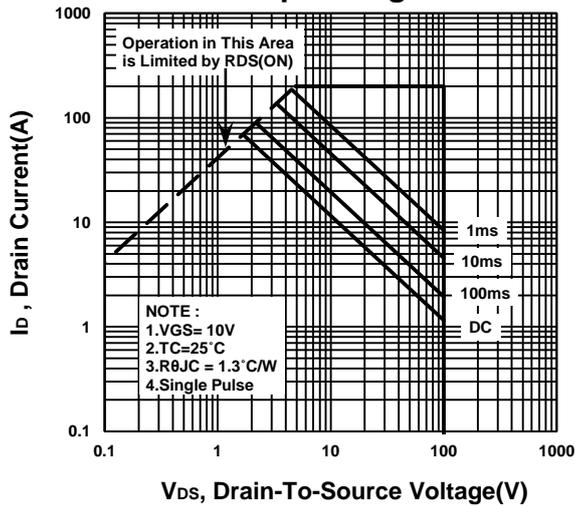
Gate charge Characteristics



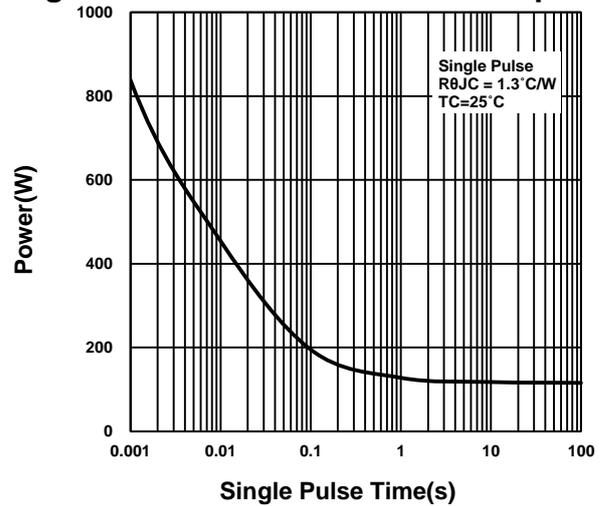
Source-Drain Diode Forward Voltage



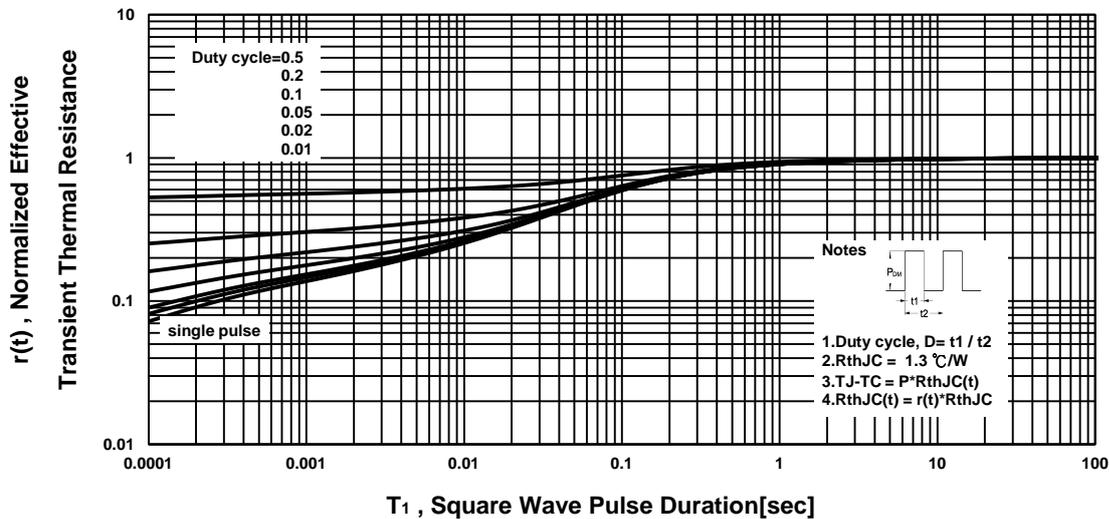
Safe Operating Area



Single Pulse Maximum Power Dissipation



Transient Thermal Response Curve



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